Product data sheet Characteristics

XUBTAPSNL2

photoelectric sensor - transparent material - Sn 0..1.4 mm - NO or NC - cable 2m

Certifications and standards

Product certifications CE
CSA
UL

Connections

Cable length	2 m
Electrical connection	Cable

Electrical

[Us] rated supply voltage	1224 V DC reverse polarity protection	
Current consumption	45 mA no-load	
Electronic sensor type	Photo-electric sensor	
Supply circuit type	DC	
Supply voltage limits	1032 V DC	
Switching capacity in mA	100 mA overload and short-circuit protection	
Voltage drop	≤ 1.5 V closed state	

Environment

IP degree of protection	IP65 double insulation IP67 double insulation	
Ambient air temperature for operation	055 °C	
Ambient air temperature for storage	-4070 °C	
Emission	Coaxial polarised red	
Shock resistance	30 gn 11 ms IEC 60068-2-27	
Vibration resistance	7 gn +/- 1 mm 1055 Hz IEC 60068-2-6	
RoHS EUR conformity date	0724	
RoHS EUR status	Compliant	

Functional

[Sn] nominal sensing distance	01.4 m with reflector XUZ C50/C50HP
Beam angle	1.5 °
Blind zone	0 mm
Discrete output function	1 NO or 1 NC programmable
Discrete output type	PNP
Kit composition	Reflector XUZC50HP Sensor
Line of sight type	Along case axis
Output type	Solid state

Status LED	1 LED yellow output state
	1 LED green supply on
	1 LED red stability
Type of output signal	Discrete
Wiring technique	3-wire
Performance	
Delay first up	< 200 ms
Delay recovery	< 500 μs
Delay response	< 500 μs
Switching frequency	1000 Hz
Physical characteristics Enclosure material	PBT
-	PBT
Lens material	PMMA
Material	Plastic
Product weight	0.11 kg
Spot diameter	37 mm
Wire insulation material	PvR
Product identification	
Range of product	Osiris
Sensor design	Design 18
Sensor name	XUBT
0. /	Application
Series name	
Usage / Application	